2SB0970 (2SB970)

Silicon PNP epitaxial planar type

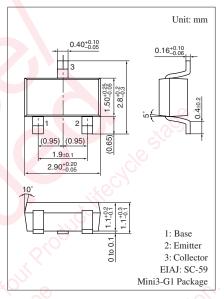
For low-voltage output amplification

■ Features

- Low collector-emitter saturation voltage V_{CE(sat)}
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V_{CBO}	-15	V	
Collector-emitter voltage (Base open)	V_{CEO}	-10	V	
Emitter-base voltage (Collector open)	V_{EBO}	-7	V	
Collector current	I_{C}	- 0.5	A	
Peak collector current	I_{CP}	-1	A	
Collector power dissipation	P_{C}	200	mW	
Junction temperature	T _j	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	



Marking Symbol: 1R

■ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = -10 \; \mu \text{A}, \; I_{\rm E} = 0$	-15	~0//		V
Collector-emitter voltage (Base open)	V_{CEO}	$I_{\rm C} = -1 \text{ mA}, I_{\rm B} = 0$	-10	0.7		V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = -10 \mu\text{A}, I_C = 0$	-7			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = -10 \text{ V}, I_E = 0$	7.7		-100	nA
Forward current transfer ratio *1	h _{FE1} *2	$V_{CE} = -2 \text{ V}, I_{C} = -0.5 \text{ A}$	130		350	_
	h _{FE2}	$V_{CE} = -2 \text{ V}, I_{C} = -1 \text{ A}$	60			_
Collector-emitter saturation voltage *1	V _{CE(sat)}	$I_C = -0.4 \text{ A}, I_B = -8 \text{ mA}$		- 0.16	- 0.30	V
Base-emitter saturation voltage *1	V _{BE(sat)}	$I_C = -0.4 \text{ A}, I_B = -8 \text{ mA}$		- 0.8	-1.2	V
Transition frequency	f_T	$V_{CB} = -10 \text{ V}, I_E = 50 \text{ mA}, f = 200 \text{ MHz}$		130		MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		22		pF
(Common base, input open circuited)		16.0 K				

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

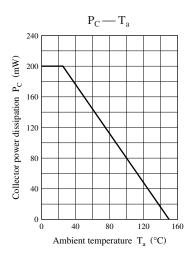
2. *1: Pulse measurement

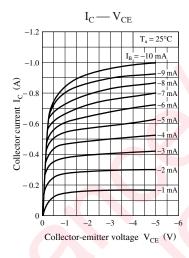
*2: Rank classification

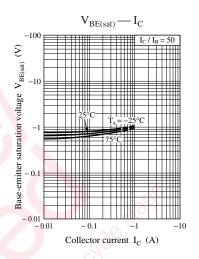
Rank	R	S	
h _{FE1}	130 to 220	20 180 to 350	

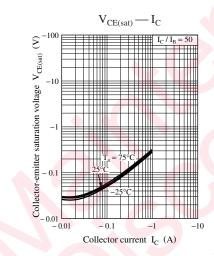
Note) The part number in the parenthesis shows conventional part number.

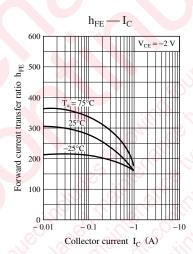
Panasonic

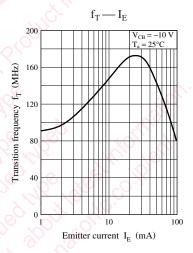


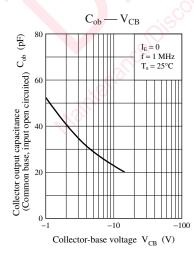












2 SJC00063BED

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